### SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SN54ALVTH16244 . . . WD PACKAGE

SN74ALVTH16244 . . . DGG, DGV, OR DL PACKAGE

(TOP VIEW)

10F L

1Y1 🛮

1Y2 🛛 3

GND 🛮 4

1Y3 🛮 5

1Y4 🛮 6

V<sub>CC</sub>  $\square$  7

2Y1 🛮 8

2Y2 🛮 9

GND 1 10

2Y3 🛮 11

2Y4 🛮 12

3Y1 [] 13

3Y2 🛮 14

GND [

3Y3 🛚

3Y4

v<sub>cc</sub>[ 18

4Y1 19

4Y2 🛮 20

GND 1 21

4Y3 22

4Y4 🛮 23

4<del>0E</del> 24

15

17

SCES070G - JUNE 1996 - REVISED MAY 1999

48 20E

47 🛮 1A1

46 1 1A2

45 GND

44 🛮 1A3

43 🛮 1A4

42 V<sub>CC</sub>

41 2A1

40 2A2

39 | GND

38 2A3

37 2A4

36 | 3A1

35 3A2

34 GND

33 | 3A3

32 3A4 31 V<sub>CC</sub>

30 4A1

29 4A2

28 GND

27 4A3

26 🛮 4A4

25 3OE

- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V **Operation and Low Static-Power** Dissipation
- 5-V I/O Compatible
- High Drive Capability (-32 mA/64 mA)
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- **Support Unregulated Battery Operation** Down to 2.3 V
- Typical V<sub>OI P</sub> (Output Ground Bounce)  $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- **Auto3-State Eliminates Bus Current Loading When Voltage at the Output** Exceeds V<sub>CC</sub>
- Ioff and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)

The 'ALVTH16244 devices are 16-bit buffers/line drivers designed for 2.5-V or 3.3-V  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Package Options Include Plastic 300-mil Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package NOTE: For tape and reel order entry: The DGGR package is abbreviated to GR, and the DGVR package is abbreviated to VR. description



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#### description (continued)

When  $V_{CC}$  is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, the output-enable  $(\overline{OE})$  input should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using  $I_{\rm off}$  and power-up 3-state. The  $I_{\rm off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

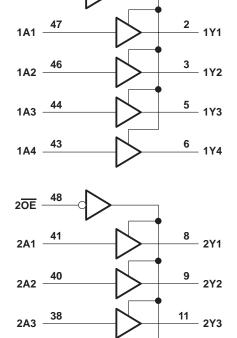
The SN54ALVTH16244 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALVTH16244 is characterized for operation from –40°C to 85°C.

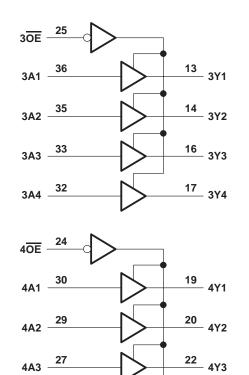
## FUNCTION TABLE (each buffer)

INP	JTS	OUTPUT
ŌĒ	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

#### logic diagram (positive logic)

2A4 —





23

4Y4



12 \_

2Y4

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	0.5 V to 4.6 V
Input voltage range, V <sub>I</sub> (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, VO (see Note 1) .	$\dots$ -0.5 V to V <sub>CC</sub> to 7V
Output current in the low state, IO: SN54ALVTH16244	
SN74ALVTH16244	128 mA
Output current in the high state, IO: SN54ALVTH16244	
SN74ALVTH16244	–64 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DGG package	89°C/W
DGV package	93°C/W
	94°C/W
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (see Note 3)

			SN54ALV	ГН16244	SN74ALVT	H16244	UNIT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.3	2.7	2.3	2.7	V
VIH	High-level input voltage	1.7	2	1.7		V	
V <sub>IL</sub>	Low-level input voltage			0.7		0.7	V
VI	Input voltage	0	5.5	0	5.5	V	
IOH	High-level output current		1	-6		-8	mA
lo	Low-level output current		2	6		8	mA
lor	Low-level output current; current duty cycle ≤ 50%; f ≥	1 kHz	70,	18		24	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
Δt/ΔVCC	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCES070G - JUNE 1996 - REVISED MAY 1999

## recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 3.3 V $\pm$ 0.3 V (see Note 3)

			SN54ALV	ГН16244	SN74ALVT	H16244	UNIT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		3	3.6	3	3.6	V
VIH	High-level input voltage		2	2	2		V
V <sub>IL</sub>	Low-level input voltage		8.0		0.8	V	
VI	Input voltage	0	5.5	0	5.5	V	
loн	High-level output current		7	-24		-32	mA
lou	Low-level output current		20	24		32	mA
lor	Low-level output current; current duty cycle ≤ 50%; f ≥	1 kHz	70,	48		64	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
Δt/ΔVCC	CC Power-up ramp rate				200		μs/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted)

DA	DAMETED	TEST OF	NUNTIONS	SN54	ALVTH1	6244	SN74	ALVTH1	6244	UNIT	
PAI	RAMETER	lESI CC	ONDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNII	
٧ıK		$V_{CC} = 2.3 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0	.2		V <sub>CC</sub> -0	.2			
Vон		V <sub>CC</sub> = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.8						V	
		VCC = 2.3 V	$I_{OH} = -8 \text{ mA}$				1.8				
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OL} = 100  \mu A$			0.2			0.2		
			$I_{OL} = 6 \text{ mA}$			0.4					
VOL		V <sub>CC</sub> = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V	
		V(C) = 2.3 V	$I_{OL} = 18 \text{ mA}$			0.5					
			$I_{OL} = 24 \text{ mA}$				0.5				
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
1.	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V <sub>I</sub> = 5.5 V			\$ 10			10	μΑ	
łį	Data inputs	V <sub>CC</sub> = 2.7 V	AI = ACC		, Š	1			1	μΑ	
	Data inputs	VCC = 2.7 V	V <sub>I</sub> = 0		72	<b>-</b> 5			<b>–</b> 5		
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 4.5 $V$		1				±100	μΑ	
		V <sub>CC</sub> = 2.3 V	V <sub>I</sub> = 0.7 V		115			115			
I <sub>I(hold)</sub>	Data inputs	VCC = 2.3 V	V <sub>I</sub> = 1.7 V	<del>-10</del>			-10			μΑ	
, ,		$V_{CC} = 2.7 V^{\ddagger}$ ,	$V_{I} = 0 \text{ to } 2.7 \text{ V}$	Q		±300			±300		
I <sub>EX</sub> §		$V_{CC} = 2.3 \text{ V},$	$V_0 = 5.5 V$			125			125	μΑ	
IOZ(PU	<sub>/PD)</sub> ¶	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} =$	to V <sub>CC</sub> , don't care			±100			±100	μΑ	
lozh		V <sub>CC</sub> = 2.7 V	$V_O = 2.3 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			5			5	μΑ	
lozL		V <sub>CC</sub> = 2.7 V	V <sub>O</sub> = 0.5 V, V <sub>I</sub> = 0.7 V or 1.7 V			<b>-</b> 5			<b>-</b> 5	μΑ	
		V <sub>CC</sub> = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1		
ICC		$I_{\Omega} = 0$ ,	Outputs low		2.3	4.5		2.3	4.5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V <sub>CC</sub> = 2.5 V,	V <sub>I</sub> = 2.5 V or 0		3			3		рF	
Со		V <sub>CC</sub> = 2.5 V,	V <sub>O</sub> = 2.5 V or 0		6			6		pF	
			<del>-</del>								

 $<sup>\</sup>uparrow$  All typical values are at V<sub>CC</sub> = 2.5 V, T<sub>A</sub> = 25°C.



<sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

 $<sup>\</sup>S$  Current into an output in the high state when  $V_O > V_{CC}$ 

<sup>¶</sup> High-impedance state during power up/power down

### SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCES070G - JUNE 1996 - REVISED MAY 1999

## electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS			ALVTH1	6244	SN74	ALVTH1	6244	LINUT	
PAR	RAMETER	l lesi c	CONDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK		V <sub>CC</sub> = 3 V,	I <sub>I</sub> = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0	.2		V <sub>CC</sub> -0	.2			
Vон		V 2.V	I <sub>OH</sub> = -24 mA	2						V	
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2				
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I <sub>OL</sub> = 100 μA			0.2			0.2		
			I <sub>OL</sub> = 16 mA						0.4		
/.			$I_{OL} = 24 \text{ mA}$			0.5				V	
VOL		V <sub>CC</sub> = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V	
			I <sub>OL</sub> = 48 mA			0.55					
			$I_{OL} = 64 \text{ mA}$						0.55		
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10		
lį			V <sub>I</sub> = 5.5 V	T		20			20	μΑ	
	Data inputs	V <sub>CC</sub> = 3.6 V	VI = VCC	T	1				1		
			V <sub>I</sub> = 0		E C	<b>-</b> 5			<b>-</b> 5		
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 4.5 $V$		DA				±100	μΑ	
		V 2.V	V <sub>I</sub> = 0.8 V	75	75			75			
II(hold)	Data inputs	VCC = 3 V	V <sub>I</sub> = 2 V	-75	20		-75			μΑ	
. ,		$V_{CC} = 3.6 V^{\ddagger}$ ,	$V_{I} = 0 \text{ to } 3.6 \text{ V}$	B		±500			±500		
I <sub>EX</sub> §		V <sub>CC</sub> = 3 V,	V <sub>O</sub> = 5.5 V			125			125	μΑ	
IOZ(PU/	<sub>/PD)</sub> ¶	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = 0.5 \text{ OE}$	V to V <sub>CC</sub> , = don't care			±100			±100	μΑ	
lozh		V <sub>CC</sub> = 3.6 V	V <sub>O</sub> = 3 V, V <sub>I</sub> = 0.8 V or 2 V			5			5	μΑ	
lozL		V <sub>CC</sub> = 3.6 V	V <sub>O</sub> = 0.5 V, V <sub>I</sub> = 0.8 V or 2 V			<b>-</b> 5			-5	μΑ	
		V <sub>CC</sub> = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1		
Icc		$I_{\Omega} = 0$ ,	Outputs low		3.2	5		3.2	5	mA	
	$V_I = V_{CC}$ or GND		Outputs disabled		0.07	0.1		0.07	0.1		
Δl <sub>CC</sub> #		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, On}$ Other inputs at $V_{CC}$ or				0.4			0.4	mA	
Ci		V <sub>CC</sub> = 3.3 V,	V <sub>I</sub> = 3.3 V or 0		3			3		pF	
Со		V <sub>CC</sub> = 3.3 V,	V <sub>O</sub> = 3.3 V or 0		6			6		pF	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

 $<sup>\</sup>S$  Current into an output in the high state when  $V_O > V_{CC}$ 

<sup>¶</sup> High-impedance state during power up/power down

<sup>#</sup>This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.

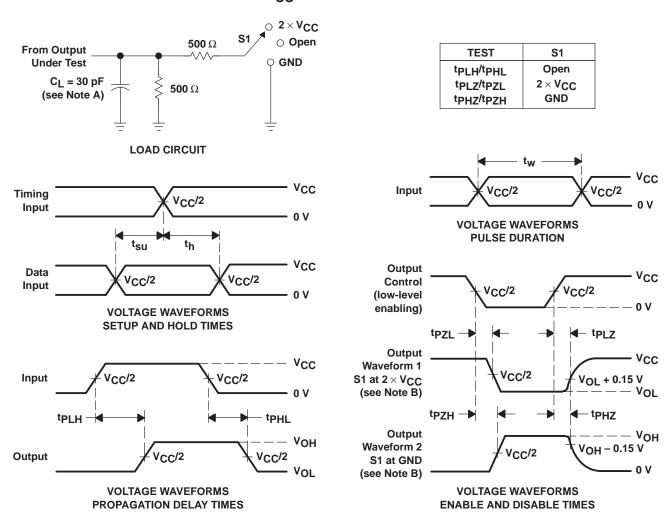
## switching characteristics over recommended operating free-air temperature range, $C_L$ = 30 pF, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALV	ГН16244	SN74ALVT	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	۸	V	1	3.1	1	3	ns
<sup>t</sup> PHL	А	ı	1	3.6	1	3.5	115
<sup>t</sup> PZH	-	V	1.1	6	1.1	5.9	ns
<sup>t</sup> PZL	OE	ı	1.150	4.8	1.1	4.7	115
<sup>t</sup> PHZ	ŌĒ	V	1.5	4.5	1.5	4.4	ns
t <sub>PLZ</sub>	OE	,	Q 1	3.5	1	3.4	110

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVT	H16244	SN74ALVT	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNII
t <sub>PLH</sub>	Α	V	1	2.6	1	2.4	ns
<sup>t</sup> PHL	A	ı	1	2.6	1	2.5	115
<sup>t</sup> PZH	-	<b>V</b>	1,0	3.9	1	3.8	ns
t <sub>PZL</sub>	OE	ı	5	3	1	2.9	115
<sup>t</sup> PHZ	ŌĒ	Y	1.5	4.3	1.5	4.2	ns
<sup>t</sup> PLZ	OE .	ı	1.5	3.7	1.5	3.6	113

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



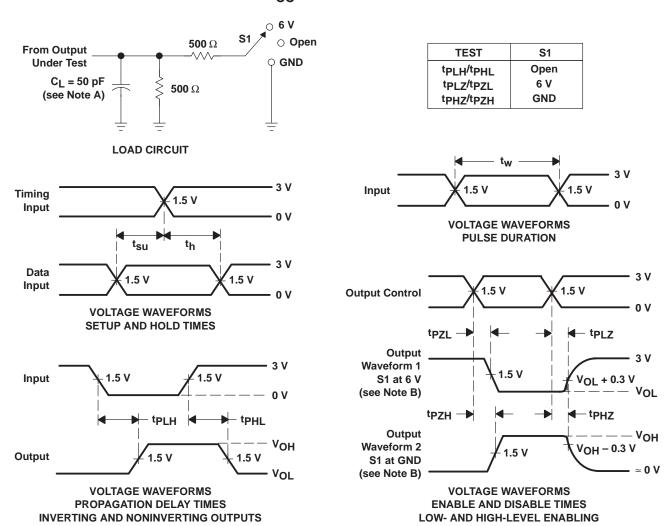
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2$  ns.  $t_f \leq 2$  ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \ \Omega$ ,  $t_\Gamma \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

#### PACKAGE OPTION ADDENDUM





#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74ALVTH16244DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244GRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244VRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16244ZQLR	ACTIVE	BGA MI CROSTA R JUNI OR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74ALVTH16244DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16244DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16244GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16244KR	NRND	BGA MI CROSTA R JUNI OR	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74ALVTH16244VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### **PACKAGE OPTION ADDENDUM**

18-Sep-2008

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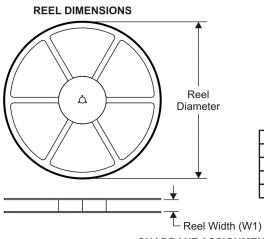
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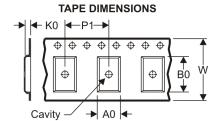




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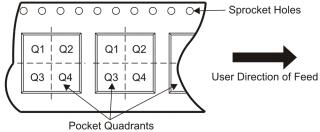
#### TAPE AND REEL INFORMATION





	Α0	Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
Г	P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74ALVTH16244ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.45	8.0	16.0	Q1
SN74ALVTH16244DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74ALVTH16244GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74ALVTH16244KR	BGA MI CROSTA R JUNI OR	GQL	56	1000	330.0	16.4	4.8	7.3	1.45	8.0	16.0	Q1
SN74ALVTH16244VR	TVSOP	DGV	48	2000	330.0	24.4	6.8	10.1	1.6	12.0	24.0	Q1





\*All dimensions are nominal

All ullilensions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74ALVTH16244ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	346.0	346.0	33.0
SN74ALVTH16244DLR	SSOP	DL	48	1000	346.0	346.0	49.0
SN74ALVTH16244GR	TSSOP	DGG	48	2000	346.0	346.0	41.0
SN74ALVTH16244KR	BGA MICROSTAR JUNIOR	GQL	56	1000	346.0	346.0	33.0
SN74ALVTH16244VR	TVSOP	DGV	48	2000	346.0	346.0	41.0

## GQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



## ZQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



#### DL (R-PDSO-G\*\*)

#### **48 PINS SHOWN**

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

### DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

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